

300 V, 100 mA PNP high-voltage transistor Rev. 6 — 27 September 2011

Product data sheet

Product profile

1.1 General description

PNP high-voltage transistor in a medium power and flat lead SOT89 (SC-62) Surface-Mounted Device (SMD) plastic package.

NPN complement: PXTA42.

1.2 Features and benefits

- High breakdown voltage
- AEC-Q101 qualified
- Medium power and flat lead SMD plastic package

1.3 Applications

- Electronic ballast for fluorescent lighting
- LED driver for LED chain module
- High Intensity Discharge (HID) front lighting
- Automotive motor management
- Hook switch for wired telecom
- Switch Mode Power Supply (SMPS)

1.4 Quick reference data

Quick reference data Table 1.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-300	V
I _C	collector current		-	-	-100	mA
I _{CM}	peak collector current		-	-	-200	mA
h _{FE}	DC current gain	$V_{CE} = -10 \text{ V};$ $I_{C} = -10 \text{ mA}$	40	-	-	



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2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	emitter		0
2	collector		. ,
3	base	3 2 1	3 ————————————————————————————————————

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PXTA92	SC-62	plastic surface-mounted package; exposed die pad for good heat transfer; 3 leads	SOT89

4. Marking

Table 4. Marking codes

Type number	Marking code[1]
PXTA92	*2D

^{[1] * =} placeholder for manufacturing site code

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	-300	V
V_{CEO}	collector-emitter voltage	open base	-	-300	V
V_{EBO}	emitter-base voltage	open collector	-	-5	V
$I_{\mathbb{C}}$	collector current		-	-100	mA
I _{CM}	peak collector current		-	-200	mA
I_{BM}	peak base current		-	-100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	<u>[1]</u> _	1300	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for collector 6 cm².

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6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] -	-	96	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	-	16	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I_{CBO}	collector-base cut-off current	$V_{CB} = -200 \text{ V}; I_E = 0 \text{ A}$	-	-	-250	nA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -3 \text{ V}; I_C = 0 \text{ A}$	-	-	-100	nA
h _{FE}	DC current gain	$V_{CE} = -10 \text{ V}; I_{C} = -1 \text{ mA}$	25	-	-	
		$V_{CE} = -10 \text{ V};$ $I_{C} = -10 \text{ mA}$	40	-	-	
		$V_{CE} = -10 \text{ V};$ $I_{C} = -30 \text{ mA}$	25	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -20 \text{ mA}; I_B = -2 \text{ mA}$	-	-	-500	mV
V _{BEsat}	base-emitter saturation voltage	$I_C = -20 \text{ mA}; I_B = -2 \text{ mA}$	-	-	-900	mV
f _T	transition frequency	$V_{CE} = -20 \text{ V};$ $I_{C} = -10 \text{ mA};$ f = 100 MHz	50	-	-	MHz
C _c	collector capacitance	$V_{CB} = -20 \text{ V};$ $I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$	-	-	6	pF

8. Test information

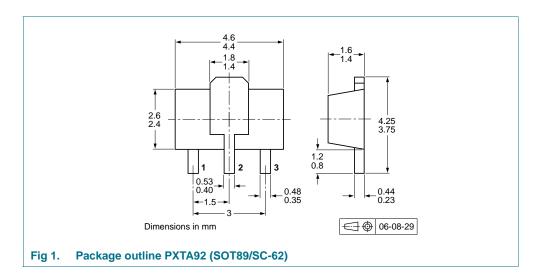
8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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9. Package outline



10. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description		Packing quantity	
				1000	4000
PXTA92	SOT89	8 mm pitch, 12 mm tape and reel; T1	[2]	-115	-135
		8 mm pitch, 12 mm tape and reel; T3	[3]	-120	-

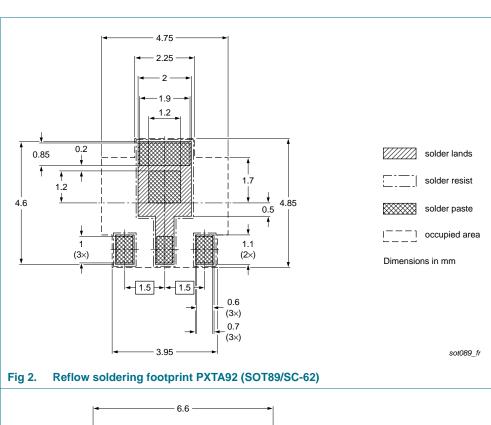
^[1] For further information and the availability of packing methods, see <u>Section 14</u>.

^[2] T1: normal taping

^[3] T3: 90° taping

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11. Soldering



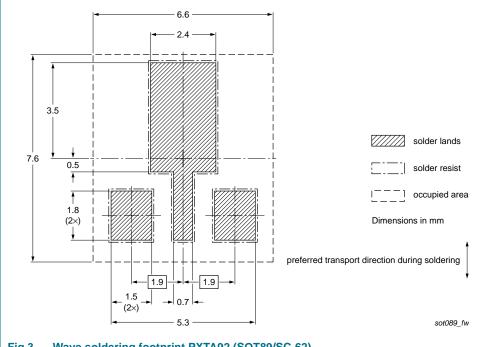


Fig 3. Wave soldering footprint PXTA92 (SOT89/SC-62)

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12. Revision history

Table 9. Revision history

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Document ID	Release date	Data sheet status	Change notice	Supersedes
PXTA92 v.6	20110927	Product data sheet	-	PXTA92 v.5
Modifications:	 Descriptive 	title corrected		
PXTA92 v.5	20110711	Product data sheet	-	PXTA92 v.4
PXTA92 v.4	20041209	Product specification	-	PXTA92 v.3
PXTA92 v.3	19990429	Product specification	-	PXTA92_93_CNV v.2
PXTA92_93_CNV v.2	19970620	Product specification	-	-

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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